AMENDMENTS TO THE CLAIMS

Claim 1. (Currently amended)

A semiconductor device comprising:

a semiconductor substrate having a front surface and rear surface, a photoelectric converting portion being formed on the front surface;

a light-shading means for shading an incoming light from the rear surface of the semiconductor substrate to said photoelectric converting portion, wherein

said light-shading means is formed at an area corresponding to at least the photoelectric converting portion, said area being on the rear surface of the semiconductor substrate, wherein the light-shading means shades the incoming light which is reflected from the rear surface of the semiconductor substrate.

Claim 2. (Previously presented)

A semiconductor device according to Claim 1, further comprising a wiring board with a connecting terminal formed on the rear surface.

Claim 3. (Original)

A semiconductor device according to Claim 1 or 2, wherein said light shading means is rough surface area.

Claim 4. (Withdrawn)

A semiconductor device according to Claim 1 or 2, wherein said light shading means is a multi-layer film composed of films with different refraction indices formed on the area corresponding to the photoelectric converting portion on the rear surface of said semiconductor substrate.

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Claim 5. (Withdrawn)

A semiconductor device according to Claim 1 or 2, wherein said light shading means is a light-shading film formed on the rear surface of said semiconductor substrate.

Claim 6. (Withdrawn)

A semiconductor device according to Claim 1 or 2, wherein said wiring board is connected to said semiconductor substrate through a light-shading resin material.

Claim 7. (Withdrawn)

A semiconductor device according to Claim 1 or 2, wherein a surface of said wiring board is rough surface.

Claim 8. (Withdrawn)

A semiconductor device according to Claim 1 or 2, wherein said wiring board includes a light shading layer in the interior or on the rear surface of the semiconductor substrate.

Claim 9-13. (Canceled)